RGPP1Q

GLASS PASSIVATED FAST RECOVERY RECTIFIER IE: 1200V CURREN

VOLTAGE: 1200V

MECHANICAL DATA

Mounting position: any

Retardant Epoxy

Polarity: color band denotes cathode

CURRENT: 1.0A

FEATURE

Molded case feature for auto insertion High current capability Low leakage current Fast switching capability High temperature soldering guaranteed 250°C /10sec/0.375" lead length at 5 lbs tension Glass Passivated chip

Terminal: Plated axial leads solderable per

MIL-STD 202E, method 208C Case: Molded with UL-94 Class V-0 recognized Flame

DO - 41\DO- 204AL 1.0(25.4)MIN $\frac{0.107(2.7)}{0.080(2.0)}$ DIA $\frac{0.205(5.2)}{0.160(4.1)}$ 1.0(25.4) MIN $\frac{0.034(0.86)}{0.028(0.71)}$ DIA Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

		SYMBOL	RGPP1Q	units
Maximum Recurrent Peak Reverse Voltage		Vrrm	1200	V
Maximum RMS Voltage		Vrms	840	V
Maximum DC blocking Voltage		Vdc	1200	V
Maximum Average Forward Rectified Current 3/8" lead length at Ta = 55 °C		lf(av)	1.0	A
Peak Forward Surge Current 8.3ms single Half sine-wave superimposed on rated load		lfsm	30.0	А
Maximum Instantaneous Forward Voltage at Rated forward current		Vf	1.3	V
Maximum DC Reverse Current At rated DC blocking voltage	Ta =25℃ Ta =100℃	Ir	5.0 100.0	μΑ μΑ
Typical Junction Capacitance	(Note 1)	Сј	15.0	pF
Maximum Reverse Recovery Time	(Note 2)	Trr	250	nS
Storage and Operating Junction Temperature		Tstg, Tj	-55 to +150	C

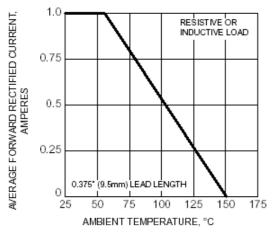
Note:

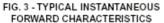
1. Measured at 1.0 MHz and applied voltage of 4.0Vdc

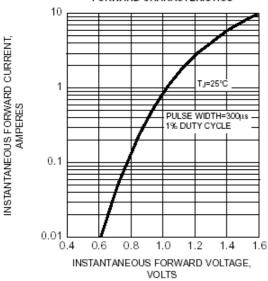
2. Test Condition If =0.5A, Ir =1.0A, Irr =0.25A

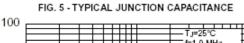


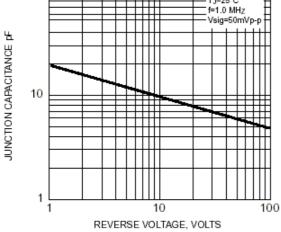
FIG. 1 - FORWARD CURRENT DERATING CURVE

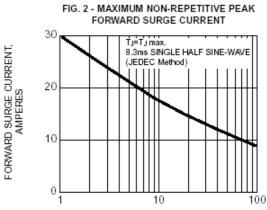




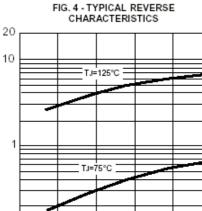








NUMBER OF CYCLES AT 60 Hz



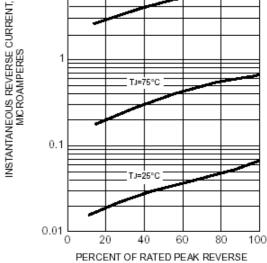
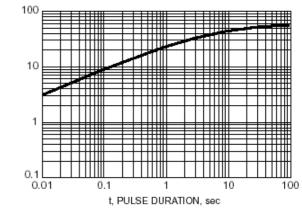


FIG. 6 - TYPICAL TRANSIENT THERMAL IMPEDANCE

VOLTAGE, %



TRANSIENT THERMAL IMPEDANCE (°CW)

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